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Power management (dual digital transistors) UMC5N / FMC5A

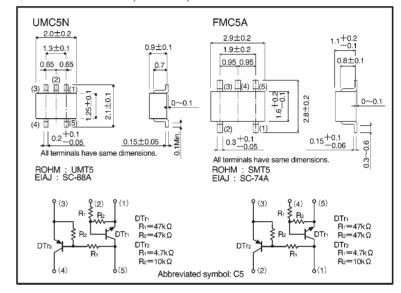
Features

- Both the DTA143X chip and DTZ144E chip in a UMT or SMT package.
- 2) Ideal for power switch circuits.
- 3) Mounting cost and area can be cut in half.

Structure

Epitaxial planar type NPN/PNP silicon transistor (Built-in resistor type)

External dimensions (Units: mm)



Absolute maximum ratings (Ta = 25°C)

Parameter		Cumbal	Lin	nits	Unit	
		Symbol	DTr ₁ (NPN)	DTr ₂ (PNP)	Offic	Offic
Supply voltage		Vcc	50	-50	V	
Input voltage		Vin	40	-20	V	
		VIN	-10	7		
Output current		IO(Max.)	30	-100	mA	
		IC(Max.)	100	-100		
Power	UMC5N	Pd	150 (TOTAL)		mW	*1
dissipation	FMC5A	Fu	300 (TOTAL)			*2
Junction temperature		Tj	150		°C	
Storange temperature		Tstg	−55∼+150		°C	

^{*1 120}mW per element must not be exceeded.

^{*2 200}mW per element must not be exceeded.

Transistors UMC5N / FMC5A

●Electrical characteristics, DTr₁ (Ta = 25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions	
Input voltage	VI (off)	_	_	0.5	V	Vcc=5V, Io=100 μ A	
Input voltage	VI (on)	3	_	_	V	Vo=0.3V, Io=2mA	
Output voltage	V _O (on)	_	0.1	0.3	٧	Io=10mA, I:=0.5mA	
Input current	lı	_	_	0.18	mA	V ₁ =5V	
Output current	lo (off)	_	_	0.5	μΑ	Vcc=50V, Vi=0V	
DC current gain	Gı	68	_	_	_	Vo=5V, Io=5mA	
Transition frequency	f⊤	_	250	_	MHz	V _{CE} =10mA, I _E =-5mA, f=100MHz *	
Input resistance	R ₁	32.9	47	61.1	kΩ	_	
Resistance ratio	R2/R1	0.8	1	1.2	_	_	

 * Transition frequency of the device

●Electrical characteristics, DTr₂ (Ta = 25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions	
Input voltogo	VI (off)	_	_	-0.3	V	Vcc=-5V, lo=-100 μ A	
Input voltage	VI (on)	-2.5	_	_	V	Vo=-0.3V, Io=-20mA	
Output voltage	Vo(on)	_	-0.1	-0.3	٧	Io=-10mA, I:=-0.5mA	
Input current	lı	_	_	-1.8	mA	V ₁ =-5V	
Output current	lo (off)	_	_	-0.5	μΑ	Vcc=-50V, Vi=0V	
DC current gain	Gı	30	_	_	_	Vo=-5V, Io=-10mA	
Transition frequency	f⊤	_	250	_	MHz	V _{CE} =-10mA, I _E =5mA, f=100MHz *	
Input resistance	R ₁	3.29	4.7	6.11	kΩ	_	
Resistance ratio	R2/R1	1.7	2.1	2.6	_	_	

^{*} Transition frequency of the device

Packaging specifications

	Packaging type	Taping		
	Code	TR	T148	
Part No.	Basic ordering unit (pieces)	3000	3000	
UMC5N		0	_	
FMC5A		_	0	

Transistors UMC5N / FMC5A

Electrical characteristic curvesDTr₁ (NPN)

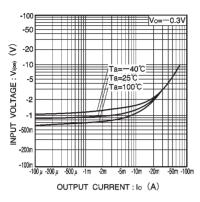


Fig.1 Input voltage vs. output current (ON characteristics)

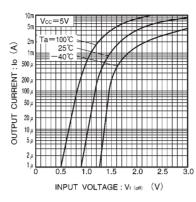


Fig.2 Output current vs. input voltage (OFF characteristics)

DTr₂ (PNP)

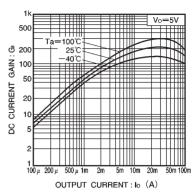


Fig.3 DC current gain vs. output current

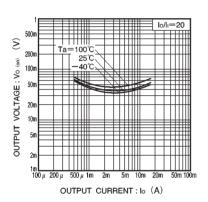


Fig.4 Output voltage vs. output current

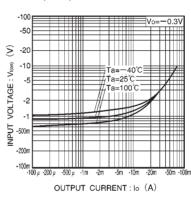


Fig.5 Input voltage vs. output current (ON characteristics)

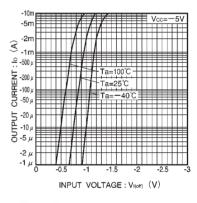


Fig.6 Output current vs. input voltage (OFF characteristics)

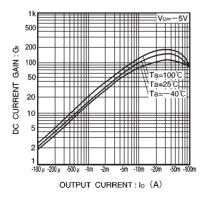


Fig.7 DC current gain vs. output current

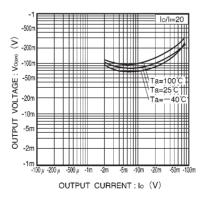


Fig.8 Output voltage vs. output current